## **Analog Power**

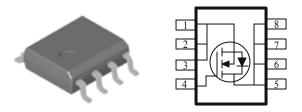
## AM4430N

## N-Channel 30-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low r<sub>DS(on)</sub> provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe SOIC-8 saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	) $r_{DS(on)} m(\Omega)$ $I_D (A)$			
30	$13.5 @ V_{GS} = 4.5V$	13		
	$20 @ V_{GS} = 2.5V$	11		



ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Limit	Units	
Drain-Source Voltage		$V_{DS}$	30	V	
Gate-Source Voltage		V <sub>GS</sub>	±12	v	
Continuous Drain Current <sup>a</sup>	$T_A=25^{\circ}C$	I.	±13		
Continuous Drain Current	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	ID	±11	А	
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	±50		
Continuous Source Current (Diode Conduction) <sup>a</sup>		Is	2.3	Α	
	$T_A=25^{\circ}C$	D_	3.1	W	
Power Dissipation <sup>a</sup>	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	гD	2.2	٧V	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Maximum	Units	
Maximum Junction-to-Case <sup>a</sup>	t <= 5 sec	$R_{\theta JC}$	25	°C/W	
Maximum Junction-to-Ambient <sup>a</sup>	t <= 5 sec	$R_{\theta JA}$	50	°C/W	

Notes

a. Surface Mounted on 1" x 1" FR4 Board.

b. Pulse width limited by maximum junction temperature

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Domorro 40 m			Limits			TL. 4	
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Threshold Voltage	VGS(th)	$V_{DS} = V_{GS}, I_D = 250 \text{ uA}$	1			V	
Gate-Body Leakage	Igss	$V_{DS} = 0 V, V_{GS} = 12 V$			±100	nA	
Zara Cata Valtaga Drain Current	Idss	$V_{DS} = 24 V, V_{GS} = 0 V$			1	uA	
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = 24 V, V_{GS} = 0 V, T_J = 55^{\circ}C$			25	uA	
On-State Drain Current <sup>A</sup>	ID(on)	$V_{DS} = 5 V, V_{GS} = 10 V$	20			Α	
		$V_{GS} = 10 V$ , $I_D = 10 A$			13.5		
Drain-Source On-Resistance <sup>A</sup>	rDS(on)	$V_{GS} = 4.5 V$ , $I_D = 8 A$			20	mΩ	
		$V_{GS} = 10 \text{ V}, I_D = 15 \text{ A}, T_J = 55^{\circ} \text{C}$			15	Ī	
Forward Tranconductance <sup>A</sup>	gś	$V_{DS} = 15 \text{ V}, I_D = 10 \text{ A}$		40		S	
Diode Forward Voltage	Vsd	$I_S = 2.3 A, V_{GS} = 0 V$		0.7		V	
Dynamic <sup>b</sup>							
Total Gate Charge	Qg	$V_{\text{DS}} = 15 \text{ V} \text{ V}_{\text{DS}} = 45 \text{ V}$		12.5		nC	
Gate-Source Charge	Qgs	$V_{DS} = 15 V, V_{GS} = 4.5 V,$ $I_D = 10 A$		2.6			
Gate-Drain Charge	Qgd	ID = 10 A		4.6			
Switching							
Turn-On Delay Time	t <sub>d(on)</sub>			20		nS	
Rise Time	tr	$V_{DD}$ = 25 V, $R_L$ = 25 $\Omega$ , $I_D$ = 1 A,		9			
Turn-Off Delay Time	td(off)	$V_{GEN} = 10 V$		70			
Fall-Time	tf			20			

Notes

- a. Pulse test:  $PW \le 300$  us duty cycle  $\le 2\%$ .
- b. Guaranteed by design, not subject to production testing.

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